

Product data sheet

## 1. Product profile

#### 1.1 General description

Silicon Monolithic Microwave Integrated Circuit (MMIC) wideband amplifier with internal matching circuit in a 6-pin SOT363 plastic SMD package.

#### 1.2 Features and benefits

- Internally matched to 50  $\Omega$
- A gain of 24.4 dB at 2150 MHz
- Output power at 1 dB gain compression = 5 dBm at 2150 MHz
- Supply current = 20.0 mA at a supply voltage of 3.3 V
- Reverse isolation > 39 dB up to 2150 MHz
- Good linearity with low second order and third order products
- Noise figure = 3.9 dB at 950 MHz
- Unconditionally stable (K > 1)
- No output inductor required

### 1.3 Applications

- LNB IF amplifiers
- General purpose low noise wideband amplifier for frequencies between DC and 2.2 GHz

# 2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	Vcc		
2, 5	GND2	6 5 4	
3	RF_OUT		6—
4	GND1		4 2, 5
6	RF_IN	□1 □2 □3	4   2, 5 //7 //7 sym052
			Symosz



#### **MMIC** wideband amplifier

# 3. Ordering information

Table 2. Ordering information

Type number	Package					
	Name	Description	Version			
BGA2817	-	plastic surface-mounted package; 6 leads	SOT363			

# 4. Marking

Table 3. Marking

Type number	Marking code	Description
		•
BGA2817	LS*	* = - : made in Hong Kong
		* = p : made in Hong Kong
		* = W : made in China
		* = t : made in Malaysia

# 5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage	RF input AC coupled	-0.5	+5.0	V
I <sub>CC</sub>	supply current		-	55	mΑ
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 90 °C	-	200	mW
T <sub>stg</sub>	storage temperature		-40	+125	°C
Tj	junction temperature		-	125	°C
P <sub>drive</sub>	drive power		-	10	dBm

### 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	$P_{tot} = 200 \text{ mW}; T_{sp} = 90 ^{\circ}\text{C}$	300	K/W

### 7. Characteristics

Table 6. Characteristics

 $V_{\text{CC}} = 3.3 \text{ V; } Z_{\text{S}} = Z_{\text{L}} = 50 \text{ } \Omega; P_{\text{i}} = -40 \text{ dBm; } T_{\text{amb}} = 25 \text{ } ^{\circ}\text{C; } \text{measured on demo board; } \text{unless otherwise specified.}$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage			3.3	3.6	V
I <sub>CC</sub>	supply current		17.6	20.0	22.2	mA

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Table 6. Characteristics ...continued

 $V_{CC} = 3.3 \text{ V}; Z_S = Z_L = 50 \Omega; P_i = -40 \text{ dBm}; T_{amb} = 25 ^{\circ}C; \text{ measured on demo board; unless otherwise specified.}$ 

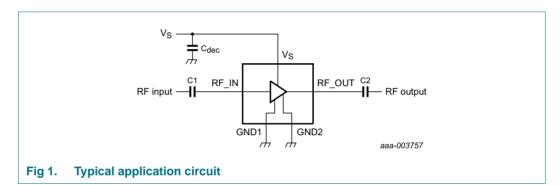
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G <sub>p</sub>	power gain	f = 250 MHz	23.6	24.2	24.8	dB
		f = 950 MHz	23.5	24.3	25	dB
		f = 2150 MHz	23	24.4	25.9	dB
RLin	input return loss	f = 250 MHz	13	15	-	dB
		f = 950 MHz	16	18	-	dB
		f = 2150 MHz	13	13       15       -         16       18       -         13       20       -         12       17       -         16       17       -         17       20       -         36       57       -         47       49       -         37       39       -         -       3.9       4         -       3.8       4         3.3       3.5       3         10       21       -         7       9       -         1.5       2.7       -         8       8       -         5       6       -         6       6       -         5       6       -         5       6       -	-	dB
RLout	output return loss	f = 250 MHz	12	17	-	dB
		f = 950 MHz	16	17	-	dB
		f = 2150 MHz	17	20	-	dB
ISL	isolation	f = 250 MHz	36	57	-	dB
		f = 950 MHz	47	49	-	dB
		f = 2150 MHz	37	23.6	-	dB
NF	noise figure	f = 250 MHz	-	3.9	4.4	dB
		f = 950 MHz	-	3.9	4.3	dB
		f = 2150 MHz	-	3.8	4.2	dB
B <sub>-3dB</sub>	-3 dB bandwidth	3 dB below gain at 1 GHz	3.3	3.5	3.7	GHz
K	Rollett stability factor	f = 250 MHz	10	21	-	
K		f = 950 MHz	7	9	-	
		f = 2150 MHz	1.5	2.7	-	
P <sub>L(sat)</sub>	saturated output power	f = 250 MHz	8	8	-	dBm
P <sub>L(sat)</sub>		f = 950 MHz	5	7	-	dBm
		f = 2150 MHz	5	6	-	dBm
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	f = 250 MHz	6	6	-	dBm
, ,		f = 950 MHz	5	6	-	dBm
		f = 2150 MHz	4	5 7 5 6 6 6 5 6	-	dBm
IP3 <sub>I</sub>	input third-order intercept point	P <sub>drive</sub> = -40 dBm (for each tone)				
		f <sub>1</sub> = 250 MHz; f <sub>2</sub> = 251 MHz	-9	-7	-	dBm
		f <sub>1</sub> = 950 MHz; f <sub>2</sub> = 951 MHz	-9	-7	-	dBm
		f <sub>1</sub> = 2150 MHz; f <sub>2</sub> = 2151 MHz	-13	-10	-	dBm
IP3 <sub>O</sub>	output third-order intercept point	P <sub>drive</sub> = -40 dBm (for each tone)				
		f <sub>1</sub> = 250 MHz; f <sub>2</sub> = 251 MHz	16	18	-	dBm
		f <sub>1</sub> = 950 MHz; f <sub>2</sub> = 951 MHz	16	18	-	dBm
		f <sub>1</sub> = 2150 MHz; f <sub>2</sub> = 2151 MHz	12.5	15.5	-	dBm
P <sub>L(2H)</sub>	second harmonic output power	P <sub>drive</sub> = -28 dBm				
7		f <sub>1H</sub> = 250 MHz; f <sub>2H</sub> = 500 MHz	-	-53	-51	dBm
		f <sub>1H</sub> = 950 MHz; f <sub>2H</sub> = 1900 MHz	-	-45	-41	dBm
ΔΙΜ2	second-order intermodulation distance	$P_{drive} = -31 dBm (for each tone)$				
		f <sub>1</sub> = 250 MHz; f <sub>2</sub> = 251 MHz	34	36	-	dBc
		f <sub>1</sub> = 950 MHz; f <sub>2</sub> = 951 MHz	33	39	-	dBc
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# 8. Application information

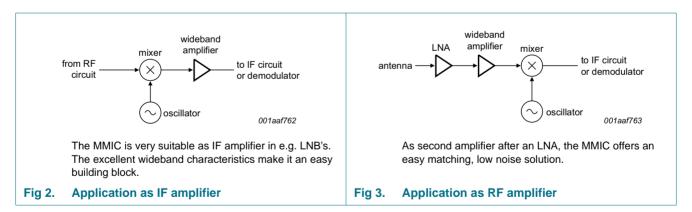
<u>Figure 1</u> shows a typical application circuit for the BGA2817 MMIC. The device is internally matched to  $50~\Omega$ , and therefore does not need any external matching. The value of the input and output DC blocking capacitors C2 and C3 should not be more than 100 pF for applications above 100 MHz. However, when the device is operated below 100 MHz, the capacitor value should be increased.

The location of the 470 pF supply decoupling capacitor (C<sub>dec</sub>) can be precisely chosen for optimum performance.

The PCB top ground plane, connected to pins 2, 4 and 5 must be as close as possible to the MMIC, preferably also below the MMIC. When using via holes, use multiple via holes as close as possible to the MMIC.



#### 8.1 Application examples



#### 8.2 Tables

Table 7. Supply current over temperature and supply voltages Typical values.

Symbol	Parameter	Conditions	T <sub>amb</sub> (°C)			Unit
			-40	+25	+85	
Icc	supply current	V <sub>CC</sub> = 3.0 V	18.0	17.6	17.3	mA
		$V_{CC} = 3.3 \text{ V}$	20.4	20.0	19.6	mA
		$V_{CC} = 3.6 \text{ V}$	22.7	22.2	21.7	mA

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**Table 8.** Second harmonic output power over temperature and supply voltages *Typical values*.

Symbol	Parameter	Conditions	T <sub>amb</sub> (°C)		Unit	
			-40	+25	+85	
P <sub>L(2H)</sub>	second harmonic output power	$f = 250 \text{ MHz}; P_{drive} = -28 \text{ dBm}$				
		V <sub>CC</sub> = 3.0 V	-38	-44	-52	dBm
		V <sub>CC</sub> = 3.3 V	-45	-53	-60	dBm
		V <sub>CC</sub> = 3.6 V	-56	-59	-53	dBm
		$f = 950 \text{ MHz}; P_{drive} = -28 \text{ dBm}$				
		V <sub>CC</sub> = 3.0 V	-43	-53	-45	dBm
		V <sub>CC</sub> = 3.3 V	-51	-45	-41	dBm
		V <sub>CC</sub> = 3.6 V	-44	-41	-39	dBm

Table 9. Input power at 1 dB gain compression over temperature and supply voltages *Typical values*.

Symbol	Parameter	Conditions	T <sub>amb</sub>	T <sub>amb</sub> (°C)		
			-40	+25	+85	
P <sub>i(1dB)</sub>	input power at 1 dB gain compression	f = 250 MHz				
		V <sub>CC</sub> = 3.0 V	-19	-18	-18	dBm
		V <sub>CC</sub> = 3.3 V	-17	-17	-17	dBm
		V <sub>CC</sub> = 3.6 V	-16	-16	-16	dBm
		f = 950 MHz				
		V <sub>CC</sub> = 3.0 V	-19	-18	-18	dBm
		V <sub>CC</sub> = 3.3 V	-18	-17	-17	dBm
		V <sub>CC</sub> = 3.6 V	-17	-17	-17	dBm
		f = 2150 MHz				
		V <sub>CC</sub> = 3.0 V	-20	-20	-20	dBm
		V <sub>CC</sub> = 3.3 V	-19	-19	-20	dBm
		V <sub>CC</sub> = 3.6 V	-18	-19	-20	dBm

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Table 10. Output power at 1 dB gain compression over temperature and supply voltages *Typical values*.

Symbol	Parameter	Conditions	T <sub>amb</sub>	T <sub>amb</sub> (°C)		Unit
			-40	+25	+85	
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	f = 250 MHz				
		V <sub>CC</sub> = 3.0 V	4	5	5	dBm
		$V_{CC} = 3.3 \text{ V}$	6	6	6	dBm
		V <sub>CC</sub> = 3.6 V	8	8	7	dBm
		f = 950 MHz				
		V <sub>CC</sub> = 3.0 V	4	4	4	dBm
		V <sub>CC</sub> = 3.3 V	6	6	6	dBm
		V <sub>CC</sub> = 3.6 V	7	7	7	dBm
		f = 2150 MHz				
		V <sub>CC</sub> = 3.0 V	4	4	3	dBm
		V <sub>CC</sub> = 3.3 V	6	5	4	dBm
		V <sub>CC</sub> = 3.6 V	7	6	5	dBm

Table 11. Saturated output power over temperature and supply voltages *Typical values*.

Symbol	Parameter	Conditions	T <sub>amb</sub>	(°C)		Unit
			-40	+25	+85	
P <sub>L(sat)</sub>	saturated output power	f = 250 MHz				
		V <sub>CC</sub> = 3.0 V	6	6	7	dBm
		V <sub>CC</sub> = 3.3 V	8	8	8	dBm
		V <sub>CC</sub> = 3.6 V	9	9	9	dBm
		f = 950 MHz				
		V <sub>CC</sub> = 3.0 V	6	6	6	dBm
		V <sub>CC</sub> = 3.3 V	7	7	7	dBm
		V <sub>CC</sub> = 3.6 V	7	8	8	dBm
		f = 2150 MHz				
		V <sub>CC</sub> = 3.0 V	5	5	4	dBm
		V <sub>CC</sub> = 3.3 V	7	6	5	dBm
		V <sub>CC</sub> = 3.6 V	8	7	6	dBm

**Table 12.** Second-order intermodulation distance over temperature and supply voltages *Typical values*.

Symbol	Parameter	Conditions	T <sub>amb</sub> (°C)			Unit
			-40	+25	+85	
ΔΙΜ2	second-order intermodulation distance	f <sub>1</sub> = 250 MHz; f <sub>2</sub> = 251 MHz; P <sub>drive</sub> = -31 dBm				
		V <sub>CC</sub> = 3.0 V	28	32	36	dBc
		V <sub>CC</sub> = 3.3 V	33	36	40	dBc
		V <sub>CC</sub> = 3.6 V	38	40	44	dBc
	f <sub>1</sub> = 950 MHz; f <sub>2</sub> = 951 MHz; P <sub>drive</sub> = -31 dBm					
		V <sub>CC</sub> = 3.0 V	29	34	40	dBc
		V <sub>CC</sub> = 3.3 V	35	39	43	dBc
		V <sub>CC</sub> = 3.6 V	40	44	42	dBc

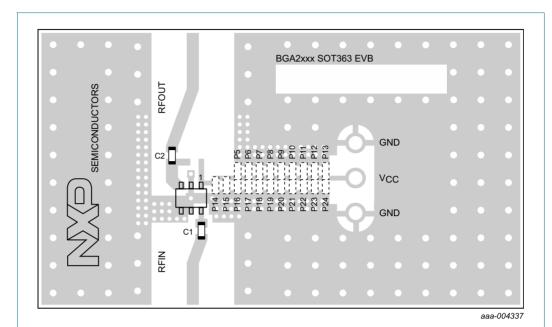
Table 13. Output third-order intercept point over temperature and supply voltages *Typical values*.

Symbol	Parameter	Conditions	T <sub>amb</sub>	T <sub>amb</sub> (°C)		
			-40	+25	+85	
IP3 <sub>O</sub>	output third-order intercept point	$f_1 = 250 \text{ MHz};$ $f_2 = 251 \text{ MHz};$ $P_{drive} = -40 \text{ dBm}$				
		$V_{CC} = 3.0 \text{ V}$	14	15	16	dBm
		$V_{CC} = 3.3 \text{ V}$	18	18	17	dBm
		V <sub>CC</sub> = 3.6 V	19	19	19	dBm
		$f_1 = 950 \text{ MHz};$ $f_2 = 951 \text{ MHz};$ $P_{drive} = -40 \text{ dBm}$				
		$V_{CC} = 3.0 \text{ V}$	15	16	15	dBm
		$V_{CC} = 3.3 \text{ V}$	18	18	17	dBm
		V <sub>CC</sub> = 3.6 V	20	20	18	dBm
		$f_1 = 2150 \text{ MHz};$ $f_2 = 2151 \text{ MHz};$ $P_{drive} = -40 \text{ dBm}$				
		$V_{CC} = 3.0 \text{ V}$	15.5	14.5	12.5	dBm
		$V_{CC} = 3.3 \text{ V}$	17.5	15.5	13.5	dBm
		V <sub>CC</sub> = 3.6 V	18.5	16.5	13.5	dBm

Table 14. –3 dB bandwidth over temperature and supply voltages *Typical values*.

Symbol	Parameter	Conditions	T <sub>amb</sub> (°C)			Unit
			-40	+25	+85	
B <sub>-3dB</sub>	-3 dB bandwidth	$V_{CC} = 3.0 \text{ V}$	3.6	3.49	3.34	GHz
		$V_{CC} = 3.3 \text{ V}$	3.59	3.47	3.32	GHz
		$V_{CC} = 3.6 \text{ V}$	3.58	3.46	3.31	GHz

### 9. Test information



For decoupling a decoupling capacitor ( $C_{dec}$ ) is used on one of the positions of P5 to P24. The results mentioned in this data sheet have been obtained using the decoupling capacitor  $C_{dec}$  on position P22. The distance between the center of pin 1 and the center of position P22 is 7.43 mm.

Fig 4. PCB layout and demo board with components

Table 15. List of components used for the typical application

Component	Description	Value	Dimensions	Remarks
C1, C2	multilayer ceramic chip capacitor	470 pF	0603	X7R RF coupling capacitor
P5 to P24 [1]	position for multilayer ceramic chip capacitor $\mathbf{C}_{\text{dec}}$	470 pF	0603	X7R RF decoupling capacitor
IC1	BGA2817 MMIC	-	SOT363	

<sup>[1]</sup> For decoupling a decoupling capacitor (C<sub>dec</sub>) is used on one of the positions of P5 to P24. The results mentioned in this data sheet have been obtained using the decoupling capacitor C<sub>dec</sub> on position P22.

**BGA2817** 

# 10. Package outline

### Plastic surface-mounted package; 6 leads

**SOT363** 

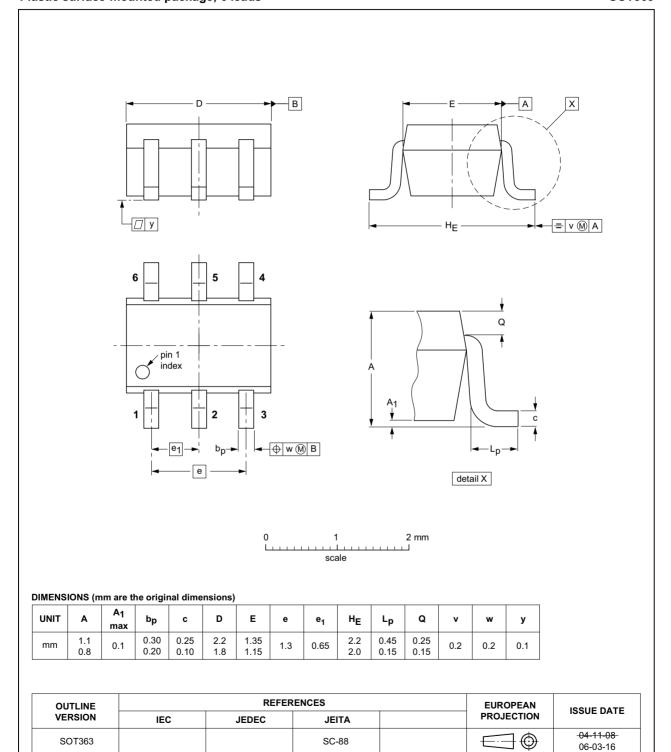


Fig 5. Package outline SOT363

### **MMIC** wideband amplifier

# 11. Abbreviations

Table 16. Abbreviations

Acronym	Description
IF	Intermediate Frequency
LNA	Low-Noise Amplifier
LNB	Low-Noise Block converter
PCB	Printed-Circuit Board
SMD	Surface Mounted Device

# 12. Revision history

#### Table 17. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BGA2817 v.7	20170330	Product data sheet	-	BGA2817 v.6		
Modifications:	Table 6 on pag to -41 dBm	e 2: the maximum value for t	1H = 950 MHz; f2H = 1	1900 MHz has been changed		
	<ul> <li><u>Table 6 on page 2</u>: the minimum value for ΔIM2 (f1 = 950 MHz; f2 = 951 MHz) has been changed to 33 dBc</li> </ul>					
	<ul> <li>Table 6 on pag</li> <li>IP3<sub>O</sub>, ΔIM2</li> </ul>	ge 2: the maximum value ren	noved from RL <sub>in</sub> , RL <sub>out</sub> ,	, ISL, K, P <sub>L(sat)</sub> , P <sub>L(1dB)</sub> , IP3 <sub>I</sub> ,		
	• Table 6 on pag	<u>je 2</u> : the minimum value rem	oved from NF, P <sub>L(2H)</sub>			
BGA2817 v.6	20161003	Product data sheet	-	BGA2817 v.5		
Modifications:	Table 6 on pag	<u>e 2</u> : the min/max value for F	$P_{L(2H)}$ ( $f_{1H} = 950 \text{ MHz}$ ; $f_{2}$	<sub>2H</sub> = 1900 MHz) removed		
	Table 6 on pag	$\underline{0}$ e 2: the min/max value for $\Delta$	IM2 ( $f_1 = 950 \text{ MHz}$ ; $f_2 = 950 \text{ MHz}$	= 951 MHz) removed		
BGA2817 v.5	20150330	Product data sheet	-	BGA2817 v.4		
Modifications:	Table 4 on pag	<u>je 2</u> : the maximum value for	P <sub>drive</sub> has been change	ed to 10 dBm		
BGA2817 v.4	20141203	Product data sheet	-	BGA2817 v.3		
BGA2817 v.3	20130826	Product data sheet	-	BGA2817 v.2		
BGA2817 v.2	20120419	Product data sheet	-	BGA2817 v.1		
BGA2817 v.1	20111117	Product data sheet	-	-		

#### **MMIC** wideband amplifier

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### **MMIC** wideband amplifier

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